



Buy







CSD18537NQ5A

SLPS391B -JUNE 2013-REVISED JULY 2014

# CSD18537NQ5A 60-V N-Channel NexFET™ Power MOSFETs

#### Features 1

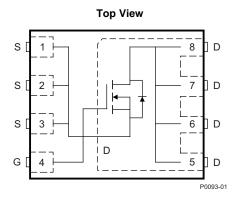
- Ultra-Low Q<sub>a</sub> and Q<sub>ad</sub>
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- **RoHS** Compliant
- Halogen Free
- SON 5 mm × 6 mm Plastic Package

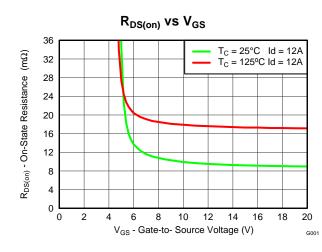
#### 2 Applications

- High-Side Synchronous Buck Converter
- Motor Control

#### Description 3

This 10 mΩ, 60 V, SON 5 mm x 6 mm NexFET™ power MOSFET is designed to minimize losses in power conversion applications.





#### **Product Summary**

T <sub>A</sub> = 25	°C	TYPICAL VA	UNIT		
V <sub>DS</sub>	Drain-to-Source Voltage 60				
Qg	Gate Charge Total (10 V)	14	nC		
Q <sub>gd</sub>	Gate Charge Gate-to-Drain 2.3				
P	Drain-to-Source On Resistance	$V_{GS} = 6 V$	13	mΩ	
R <sub>DS(on)</sub>	Drain-to-Source Off Resistance	V <sub>GS</sub> = 10 V 10		mΩ	
V <sub>GS(th)</sub>	Threshold Voltage	3		V	

#### Ordering Information<sup>(1)</sup>

Device	Qty	Media	Package	Ship
CSD18537NQ5A	2500	13-Inch Reel	SON 5 x 6 mm	Tape and
CSD18537NQ5AT	250	7-Inch Reel	Plastic Package	Reel

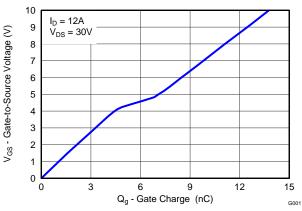
(1) For all available packages, see the orderable addendum at the end of the data sheet.

ADSUILLE MAXIMUM Ratings								
$T_A = 2$	5°C	VALUE	UNIT					
V <sub>DS</sub>	Drain-to-Source Voltage	60	V					
V <sub>GS</sub>	Gate-to-Source Voltage	±20	V					
	Continuous Drain Current (Package limited)	50						
I <sub>D</sub>	Continuous Drain Current (Silicon limited), $T_C = 25^{\circ}C$	54	А					
	Continuous Drain Current <sup>(1)</sup>	11						
I <sub>DM</sub>	Pulsed Drain Current <sup>(2)</sup>	151	А					
<u> </u>	Power Dissipation <sup>(1)</sup>	3.2	14/					
PD	Power Dissipation, $T_C = 25^{\circ}C$	75	W					
T <sub>J</sub> , T <sub>stg</sub>	Operating Junction and Storage Temperature Range	-55 to 150	°C					
E <sub>AS</sub>	Avalanche Energy, single pulse I_D = 33 A, L = 0.1 mH, R_G = 25 $\Omega$	55	mJ					

#### Absolute Maximum Ratings

(1) Typical  $R_{\theta,JA}$  = 40°C/W on a 1-inch², 2-oz. Cu pad on a 0.06-inch thick FR4 PCB.

(2) Max R<sub> $\theta$ JC</sub> = 2.1°C/W, pulse duration ≤100 µs, duty cycle ≤1%



#### **Gate Charge**

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.



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## 4 Revision History

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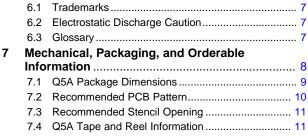
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

#### Changes from Revision A (February 2014) to Revision B

# Reduced silicon current limit to 54 A due to increase in R<sub>0JC</sub>

#### Changes from Original (June 2013) to Revision A

•	Added part number to title	1
•	Added more information to description	1
•	Updated ordering information to include small reel information	1
•	Removed T <sub>c</sub> = 25°C condition from package limited continuous drain current	1





#### Page

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# **5** Specifications

#### 5.1 Electrical Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS					
BV <sub>DSS</sub>	Drain-to-Source Voltage	$V_{GS} = 0 V, I_D = 250 \mu A$	60			V
I <sub>DSS</sub>	Drain-to-Source Leakage Current	$V_{GS} = 0 V, V_{DS} = 48 V$			1	μA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	$V_{DS} = 0 V, V_{GS} = 20 V$			100	nA
V <sub>GS(th)</sub>	Gate-to-Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	2.6	3	3.5	V
Р	Drain to Source On Registeres	$V_{GS} = 6 V, I_D = 12 A$		13	17	mΩ
R <sub>DS(on)</sub>	Drain-to-Source On Resistance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 12 \text{ A}$		10	13	mΩ
9 <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 30 V, I <sub>D</sub> = 12 A		62		S
DYNAMI	C CHARACTERISTICS					
C <sub>iss</sub>	Input Capacitance			1140	1480	pF
C <sub>oss</sub>	Output Capacitance	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 30 V, <i>f</i> = 1 MHz		136	177	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			4	5.2	pF
R <sub>G</sub>	Series Gate Resistance			5.5	11	Ω
Qg	Gate Charge Total (10 V)			14	18	nC
Q <sub>gd</sub>	Gate Charge Gate-to-Drain			2.3		nC
Q <sub>gs</sub>	Gate Charge Gate-to-Source			4.7		nC
Q <sub>g(th)</sub>	Gate Charge at V <sub>th</sub>			3.3		nC
Q <sub>oss</sub>	Output Charge	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V		25		nC
t <sub>d(on)</sub>	Turn On Delay Time			5.8		ns
t <sub>r</sub>	Rise Time			4		ns
t <sub>d(off)</sub>	Turn Off Delay Time	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 10 V, I <sub>DS</sub> = 12 A, R <sub>G</sub> = 0 Ω		14.4		ns
t <sub>f</sub>	Fall Time			3.2		ns
DIODE C	CHARACTERISTICS		•		+	
V <sub>SD</sub>	Diode Forward Voltage	I <sub>SD</sub> = 12 A, V <sub>GS</sub> = 0 V		0.8	1	V
Q <sub>rr</sub>	Reverse Recovery Charge			54		nC
t <sub>rr</sub>	Reverse Recovery Time	$V_{DS}$ = 30 V, I <sub>F</sub> = 12 A, di/dt = 300 A/µs		40		ns

#### 5.2 Thermal Information

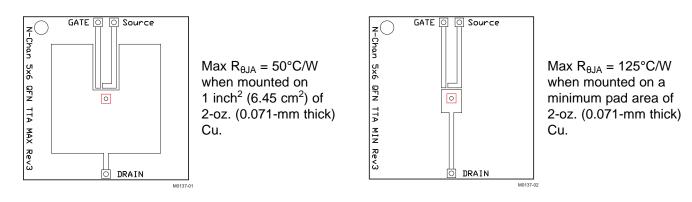
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

	THERMAL METRIC	MIN	TYP	MAX	UNIT
$R_{ extsf{ heta}JC}$	Junction-to-Case Thermal Resistance <sup>(1)</sup>			2.1	°C/W
$R_{\thetaJA}$	Junction-to-Ambient Thermal Resistance (1)(2)	<u>.</u>		50	°C/w

(1) R<sub>0JC</sub> is determined with the device mounted on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inches x 1.5-inches (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. R<sub>0JC</sub> is specified by design, whereas R<sub>0JA</sub> is determined by the user's board design.

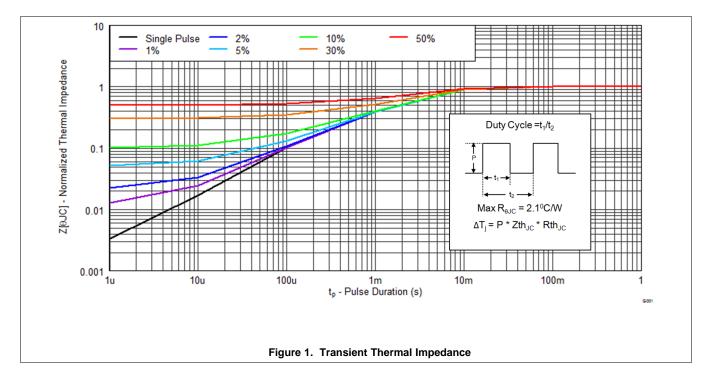
(2) Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.





# 5.3 Typical MOSFET Characteristics

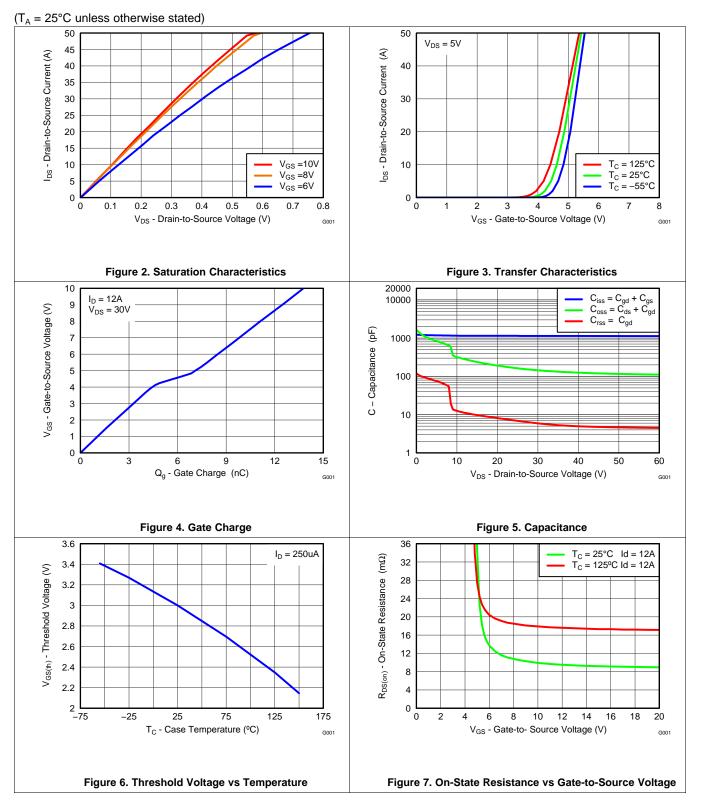
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 



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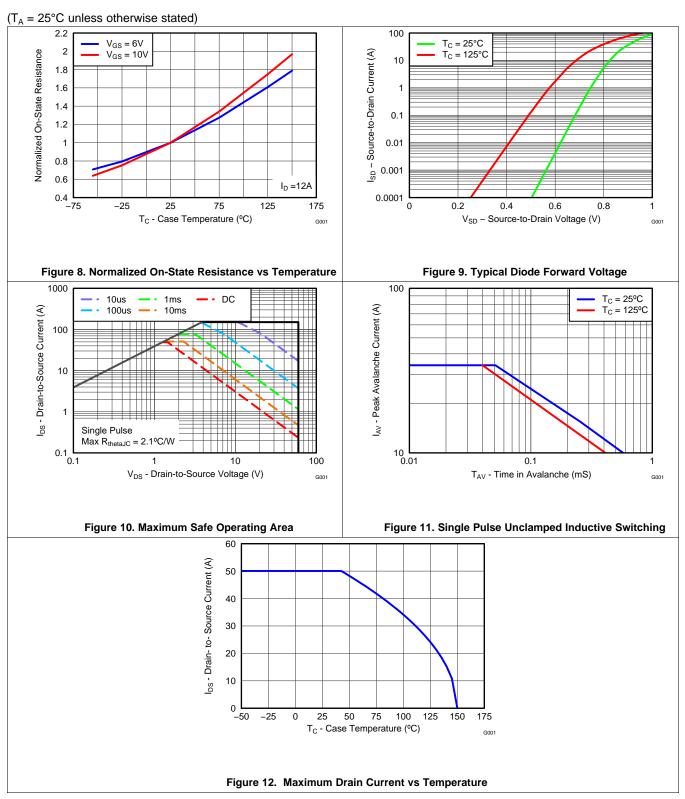


#### **Typical MOSFET Characteristics (continued)**





# **Typical MOSFET Characteristics (continued)**





# 6 Device and Documentation Support

# 6.1 Trademarks

NexFET is a trademark of Texas Instruments.

#### 6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### 6.3 Glossary

#### SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

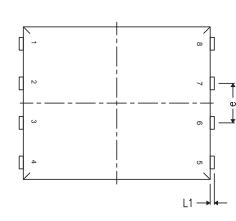


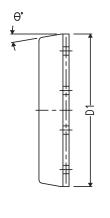
## 7 Mechanical, Packaging, and Orderable Information

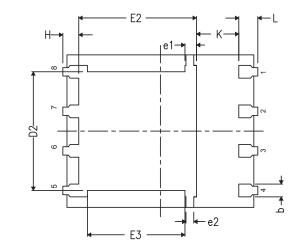
The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



# 7.1 Q5A Package Dimensions

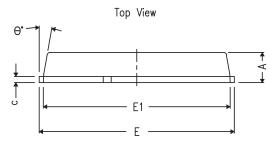






Side View

Bottom View



Front View

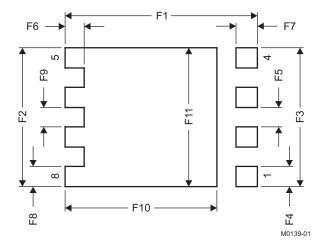
DIM	MILLIMETERS								
DIM	MIN	NOM	MAX						
A	0.90	1.00	1.10						
b	0.33	0.41	0.51						
с	0.20	0.25	0.34						
D1	4.80	4.90	5.00						
D2	3.61	3.81	4.02						
E	5.90	6.00	6.10						
E1	5.70	5.75	5.80						
E2	3.38	3.58	3.78						
E3	3.03	3.13	3.23						
е	1.17	1.27	1.37						
e1	0.27	0.37	0.47						
e2	0.15	0.25	0.35						
н	0.41	0.56	0.71						
К	1.10	—	_						
L	0.51	0.61	0.71						
L1	0.06	0.13	0.20						
θ	0°		12°						

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TEXAS INSTRUMENTS

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#### 7.2 Recommended PCB Pattern

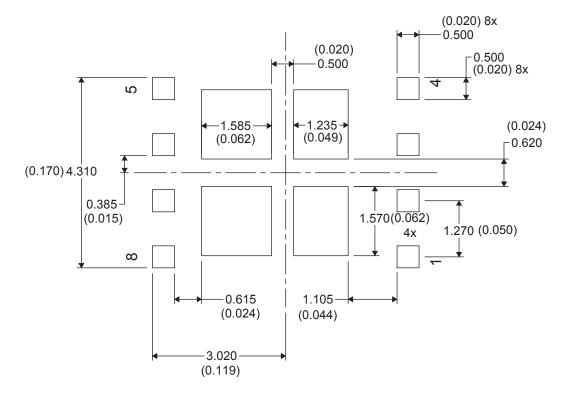


DIM	MILLIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65	0.7	0.026	0.028
F5	0.62	0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

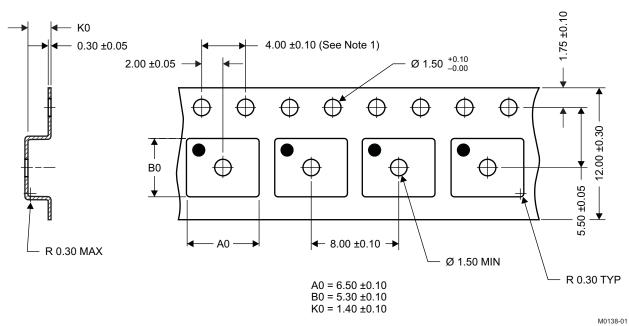
For recommended circuit layout for PCB designs, see application note SLPA005 – *Reducing Ringing Through PCB Layout Techniques*.



#### 7.3 Recommended Stencil Opening



#### 7.4 Q5A Tape and Reel Information



Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified).
- 5. A0 and B0 measured on a plane 0.3 mm above the bottom of the pocket.



28-Apr-2015

# PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD18537NQ5A	ACTIVE	VSONP	DQJ	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	18537N	Samples
CSD18537NQ5AT	ACTIVE	VSONP	DQJ	8	250	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	18537N	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

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<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(<sup>6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE OPTION ADDENDUM

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